




ROWAN GILMORE • LES BESSER

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PRACTICAL   
RF CIRCUIT  
DESIGN   
 FOR MODERN  
WIRELESS  
SYSTEMS

VOLUME II

ACTIVE CIRCUITS AND SYSTEMS



# **Practical RF Circuit Design for Modern Wireless Systems**

**Volume II**

**Active Circuits and Systems**

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# Practical RF Circuit Design for Modern Wireless Systems

Volume II

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Rowan Gilmore

Les Besser



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*To our wives, Nicole and Susan*





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